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DATE: Friday, December 10, 2004

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	DB=PGPB,	USPT,EPAB,JPAB,DWPI,TDBD; PLUR=Y.	ES; OP=ADJ
	L7	L6 and ultrasonic	7
\Box	L6	photomasks adj cleaning	61
\Box	L5	photomasks near3 cleaning	230
	L4	L3 and ultrasonic	43
	L3	L2 and solution	221
	L2	L1 and (ammonium hydroxide)	250
	L1	photomasks and cleaning	3102

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Clear Generate Collection Print Fwd Refs Bkwd Refs
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Search Results - Record(s) 1 through 7 of 7 returned.

1. Document ID: US 20030116176 A1

Using default format because multiple data bases are involved.

L7: Entry 1 of 7

File: PGPB

Jun 26, 2003

PGPUB-DOCUMENT-NUMBER: 20030116176

PGPUB-FILING-TYPE: new

DOCUMENT-IDENTIFIER: US 20030116176 A1

TITLE: Supercritical fluid processes with megasonics

PUBLICATION-DATE: June 26, 2003

INVENTOR-INFORMATION:

NAME CITY STATE COUNTRY RULE-47 Rothman, Laura B. South Kent CTUS Robey, Raymond J. Naperville US $_{
m IL}$ White, Rick Nashua NH US Mount, David J. North Andover MA US Farmer, Robert B. Hooksett NH US Pope, Keith Danbury CTUS

US-CL-CURRENT: $\underline{134}/\underline{1.3}$; $\underline{134}/\underline{157}$, $\underline{134}/\underline{184}$, $\underline{134}/\underline{26}$, $\underline{134}/\underline{34}$, $\underline{134}/\underline{95.1}$

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	Claims	KWIC	Draw, D

File: PGPB

2. Document ID: US 20020155360 A1

Oct 24, 2002

PGPUB-DOCUMENT-NUMBER: 20020155360

PGPUB-FILING-TYPE: new

L7: Entry 2 of 7

DOCUMENT-IDENTIFIER: US 20020155360 A1

TITLE: Cleaning process for photomasks

PUBLICATION-DATE: October 24, 2002

INVENTOR-INFORMATION:

NAME CITY STATE COUNTRY RULE-47

Tange, Koji Tokyo JP Nagamura, Yoshikazu Tokyo JP

h eb bgeeef eb ef b

Aug 16, 2001

Hosono, Kunihiro	Tokyo	JP
Kikuchi, Yasutaka	Tokyo	JP
Oomasa, Yuki	Tokyo	JP
Kido, Koichi	Tokyo	JP

US-CL-CURRENT: 430/5

ABSTRACT:

A photomask provided with a light-shielding coating on a surface of a glass substrate is cleaned with O.sub.3 gas solved water to eliminate organic substances adhered on a surface of the photomask (S120). Using an alkaline chemical such as alkaline ionized water or hydrogenated water, the photomask is then cleaned to eliminate contamination (S122). After completion of these cleaning steps, the photomask is dried (S124).

Full	Title	Citation	Frent	Review	Classification	Date	Reference	Sequences	Attachments	Claims	KWIC	Draw, De

File: PGPB

3. Document ID: US 20010013355 A1

PGPUB-DOCUMENT-NUMBER: 20010013355

PGPUB-FILING-TYPE: new

L7: Entry 3 of 7

DOCUMENT-IDENTIFIER: US 20010013355 A1

TITLE: Fast single-article megasonic cleaning process for single-sided or dual-

sided cleaning

PUBLICATION-DATE: August 16, 2001

INVENTOR-INFORMATION:

NAME CITY STATE COUNTRY RULE-47

Busnaina, Ahmed A. Norwood MA US

US-CL-CURRENT: <u>134/1.3</u>; <u>134/184</u>, <u>134/902</u>

ABSTRACT:

A fast single-article megasonic cleaning system (200) is used to clean substrates (such as semiconductor wafers, flat panel display glass, etc.) at frequencies of 400 kHz-20,000 kHz or higher. The technique provides a single-wafer cleaning process that reduces the cleaning time from the 10-20 minutes typical of the prior art to 15-60 seconds. The system utilizes concentrated megasonic energy on one wafer (90) to dramatically reduce cleaning time. The system uses a transducer (210) or a pair or transducers (210a, 210b) parallel to the substrate (90) to be cleaned where the transducer area is more than about 40% of the substrate area. Two alternate configurations are disclosed, one utilizing a horizontal wafer arrangement and the second utilizing a vertical wafer arrangement. The latter requires a smaller floor area. Preferred spacings between the wafer and the transducer, preferred transducer power and intensity, preferred overflow flow rate of fluid medium (220) (which may be deionized water), effective cleaning times, and

process temperature are disclosed.

Full Title Citation Fro	nt Review Classification	Date Reference	Sequences	Attachments Claims	KusiC Draw De

4. Document ID: US 6277205 B1

L7: Entry 4 of 7

File: USPT

Aug 21, 2001

US-PAT-NO: 6277205

DOCUMENT-IDENTIFIER: US 6277205 B1

TITLE: Method and apparatus for cleaning photomask

DATE-ISSUED: August 21, 2001

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP (CODE	COUNTRY
Nagamura; Yoshikazu	Tokyo				JP
Yoshioka; Nobuyuki	Tokyo				JP
Usui; Hozumi	Saitama				JP
Yamanaka; Koji	Satama				JP

US-CL-CURRENT: <u>134/3</u>; <u>134/1</u>, <u>134/2</u>, <u>134/22.19</u>, <u>134/25.4</u>, <u>134/26</u>, <u>134/28</u>, <u>134/29</u>, <u>134/36</u>, <u>134/41</u>, <u>134/42</u>, <u>134/902</u>

ABSTRACT:

To provide a <u>photomask cleaning</u> method which brings about a high effect of removing residual sulfuric acid or foreign objects and can remove foreign objects effectively without fluctuating the transmission or other properties of the light-shielding layer (MoSiON film) in a phase shift photomask.

A method of cleaning a photomask which comprises a first step of cleaning the surface of a photomask used as a master in the photolithography step in the process for the production of semiconductor device with a hot mixture of sulfuric acid and hydrogen peroxide to decompose organic objects present thereon and remove metallic impurities, a second step of removing residual sulfuric acid from the surface of said photomask, a third step of removing foreign objects attached to the surface of said photomask, and a fourth step of drying said photomask which has finished with said first, second and third steps, characterized in that said second step involves the removal of residual sulfuric acid from the surface of said photomask with anodic water and said third step involves the removal of foreign objects with cathodic water.

11 Claims, 15 Drawing figures Exemplary Claim Number: 10 Number of Drawing Sheets: 7

Full	Title	Citation	Front	Review	Classification	Date	Reference Claims KOOC Draw D	

5. Document ID: US 6071376 A

L7: Entry 5 of 7 File: USPT Jun 6, 2000

US-PAT-NO: 6071376

DOCUMENT-IDENTIFIER: US 6071376 A

TITLE: Method and apparatus for cleaning photomask

DATE-ISSUED: June 6, 2000

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Nagamura; Yoshikazu	Tokyo			JP
Yoshioka; Nobuyuki	Tokyo			JР
Usui; Hozumi	Saitama			JP
Yamanaka; Koji	Satama			JP

US-CL-CURRENT: <u>156/345.22</u>; <u>134/1.1</u>

ABSTRACT:

To provide a <u>photomask cleaning</u> method which brings about a high effect of removing residual sulfuric acid or foreign objects and can remove foreign objects effectively without fluctuating the transmission or other properties of the light-shielding layer (MoSiON film) in a phase shift photomask.

A method of cleaning a photomask which comprises a first step of cleaning the surface of a photomask used as a master in the photolithography step in the process for the production of semiconductor device with a hot mixture of sulfuric acid and hydrogen peroxide to decompose organic objects present thereon and remove metallic impurities, a second step of removing residual sulfuric acid from the surface of said photomask, a third step of removing foreign objects attached to the surface of said photomask, and a fourth step of drying said photomask which has finished with said first, second and third steps, characterized in that said second step involves the removal of residual sulfuric acid from the surface of said photomask with anodic water and said third step involves the removal of foreign objects with cathodic water.

4 Claims, 15 Drawing figures Exemplary Claim Number: 1 Number of Drawing Sheets: 7

Γ 6 Document ID: IP 05134398 Δ	6. Document ID: JP 05134398 A	Full Title Citation Front Review	Classification Date Reference	Claims KOMC Draw
6 Document ID: IP 05134398 A	6. Document ID: JP 05134398 A			
	Journal 15, 11 0515 1570 11	······································		***************************************

DERWENT-ACC-NO: 1993-209422

DERWENT-WEEK: 199326

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TITLE: Photomask cleaning device - has ultrasonic oscillator and vibration plate,

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and allow water stream given to ultrasonic vibration to flow to brush NoAbstract

PRIORITY-DATA: 1991JP-0300435 (November 15, 1991)

PATENT-FAMILY:

PUB-NO PUB-DATE

LANGUAGE

PAGES

MAIN-IPC

JP 05134398 A

May 28, 1993

004

G03F001/08

INT-CL (IPC): B08B 1/00; B08B 3/02; B08B 3/12; B44C 1/22; G03F 1/08

Full Title Citation Front Review (Classification Date Reference	Claims 10MC Draw De
		······
7. Document ID: JP 571	19347 A	
L7: Entry 7 of 7	File: DWPI	Jul 24, 1982

DERWENT-ACC-NO: 1982-73384E

DERWENT-WEEK: 198235

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TITLE: <u>Photomask cleaning</u> for mfg. semiconductor device - where two methods from mechanical, chemical, <u>ultrasonic</u> wave, and jet press cleaning are used at same time

PRIORITY-DATA: 1981JP-0006603 (January 17, 1981)

PATENT-FAMILY:

PUB-NO

PUB-DATE

LANGUAGE

PAGES

MAIN-IPC

<u>JP 57119347 A</u>

July 24, 1982

003

INT-CL (IPC): G03F 1/00; H01L 21/30

Full Title Citation Front Review Classification Date Reference	Claims KM	IC Dra
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Term	Documents	
ULTRASONIC	243683	
ULTRASONICS	10717	
(6 AND ULTRASONIC).PGPB,USPT,EPAB,JPAB,DWPI,TDBD.	7	
(L6 AND ULTRASONIC).PGPB,USPT,EPAB,JPAB,DWPI,TDBD.	7	

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Previous Page Next Page Go to Doc#

First Hit

Previous Doc

Next Doc

Go to Doc#

End of Result Set

Generate Collection

Print

L7: Entry 7 of 7

File: DWPI

Jul 24, 1982

DERWENT-ACC-NO: 1982-73384E

DERWENT-WEEK: 198235

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TITLE: Photomask cleaning for mfg. semiconductor device - where two methods from mechanical, chemical, ultrasonic wave, and jet press cleaning are used at same time

PATENT-ASSIGNEE: MITSUBISHI ELECTRIC CORP (MITQ)

PRIORITY-DATA: 1981JP-0006603 (January 17, 1981)

Search Selected Search ALL Clear

PATENT-FAMILY:

PUB-NO

PUB-DATE

LANGUAGE

PAGES

MAIN-IPC

JP 57119347 A

July 24, 1982

003

INT-CL (IPC): G03F 1/00; H01L 21/30

DERWENT-CLASS: L03 P84 U11

CPI-CODES: L03-D03B;

Previous Doc Next Doc Go to Doc#

First Hit

Previous Doc

Next Doc

Go to Doc#

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Generate Collection

Print

L7: Entry 7 of 7

File: DWPI

Jul 24, 1982

DERWENT-ACC-NO: 1982-73384E

DERWENT-WEEK: 198235

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TITLE: Photomask cleaning for mfg. semiconductor device - where two methods from mechanical, chemical, ultrasonic wave, and jet press cleaning are used at same time

Standard Title Terms (1):

PHOTOMASK CLEAN MANUFACTURE SEMICONDUCTOR DEVICE TWO METHOD MECHANICAL CHEMICAL ULTRASONIC WAVE JET PRESS CLEAN TIME

Previous Doc Next Doc Go to Doc#

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